•	Application No. Applicant(s)		
Notice of Allowability	10/735,476	735,476 TATSÜMI, MASAKI	
	Examiner	Art Unit	
	Jennifer M. Dolan	2813	(20
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI	(OR REMAINS) CLOSED in or other appropriate commu IGHTS. This application is s	n this application. If not include unication will be mailed in due	d course. THIS
1. This communication is responsive to <u>Amendment of 12/20.</u>	<u>/05</u> .		
2. ⊠ The allowed claim(s) is/are <u>1 and 3-9</u> .		·	
 3. Acknowledgment is made of a claim for foreign priority ur a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 4. A SUBSTITUTE OATH OR DECLARATION must be subm 	e been received. be been received in Application cuments have been received of this communication to file IENT of this application.	on No d in this national stage applicate a reply complying with the req	uirements
INFORMAL PATENT APPLICATION (PTO-152) which give 5. CORRECTED DRAWINGS (as "replacement sheets") mus	es reason(s) why the oath or st be submitted.	declaration is deficient.	STICE OF
(a) ☐ including changes required by the Notice of Draftspers	_	v (PTO-948) attached	
 1) ☐ hereto or 2) ☐ to Paper No./Mail Date (b) ☐ including changes required by the attached Examiner's Paper No./Mail Date 		in the Office action of	-
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in the			back) of
 DEPOSIT OF and/or INFORMATION about the depo- attached Examiner's comment regarding REQUIREMENT 	SIT OF BIOLOGICAL MATE FOR THE DEPOSIT OF BIO	ERIAL must be submitted. N DLOGICAL MATERIAL.	ote the
 Attachment(s) 1. ☐ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 10/6/05 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	6. Interview Si Paper No./ 98), 7. Examiner's	formal Patent Application (PTC ummary (PTO-413), 'Mail Date Amendment/Comment Statement of Reasons for Allog	
		CARL WHITEHEAD, JR. SUPERVISORY PATENT EXAMINI TECHNOLOGY CENTER 2800	ER

DETAILED ACTION

Election/Restrictions

1. Claims 1 and 3-6 are directed to an allowable product. Pursuant to the procedures set forth in the Official Gazette notice dated March 26, 1996 (1184 O.G. 86), claims 7-9, directed to the process of making or using the patentable product, previously withdrawn from consideration as a result of a restriction requirement, are now subject to being rejoined. Claims 7-9 are hereby rejoined and fully examined for patentability under 37 CFR 1.104.

Since all claims previously withdrawn from consideration under 37 CFR 1.142 have been rejoined, the restriction requirement made in the Office action mailed on 6/23/05 is hereby withdrawn.

Allowable Subject Matter

- 2. Claims 1 and 3-9 are allowed.
- 3. The following is an examiner's statement of reasons for allowance:

The Examiner notes and agrees with the Applicant's comments filed 12/20/05.

The Examiner further notes that the primary reason for allowability is that the prior art does not fairly suggest burying a ridge portion of a real-guide laser section with a both a semiconductor layer current blocking/GaAs type layer and a low refractive index dielectric film. The prior art generally teaches the formation of real-guide buried ridge lasers using a single insulating or

semi-insulating burying film (see US 2002/0185643 to Uchida, US 6,757,311 to Abe, or US 6,358,764 to Nemoto). There is additionally some suggestion of burying the films using a current-blocking semiconductor layer (see US 2003/0021320). Both of these prior-art methods for forming a real-guide structure are acknowledged by the Applicant in the first two paragraphs of page 3 of the specification. The prior art, however, offers no suggestion for including both a semiconductor film and a dielectric film as a burying structure, nor is there any reasonable motivation provided for combining the prior art insulating layer burying film with the prior art semiconductor layer burying film. Since the specific combination of the semiconductor layer and insulating layer as a burying structure improves the thermal characteristic and reliability of the laser (due to the presence of the semiconductor film) while maintaining high process control and ease of fabrication (due to the presence of the insulating film), it is the Examiner's opinion that the invention as claimed is well beyond the purview of a person having ordinary skill in the art.

4. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jennifer M. Dolan whose telephone number is (571) 272-1690. The examiner can normally be reached on Monday-Friday 8:30am-5:00pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl W. Whitehead, Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Jennifer M. Dolan Examiner Art Unit 2813

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